
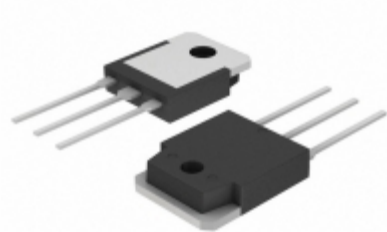

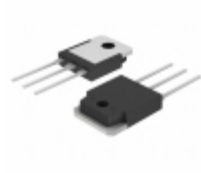

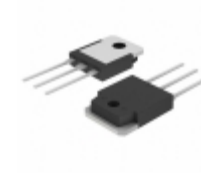
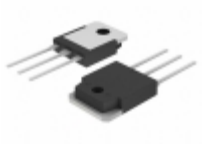


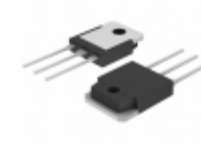
	<h2 style="color: red;">FQA47P06</h2>
	<p>Hersteller-Teilenummer: FQA47P06</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET P-CH 60V 55A TO-3PN</p> <p>Datenblätter:  FQA47P06.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 8364 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQA47P06
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET P-CH 60V 55A TO-3PN
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	8364 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-3P-3, SC-65-3
Supplier Device-Gehäuse	TO-3PN
Verlustleistung (max)	214W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	55A (Tc)
Rds On (Max) @ Id, Vgs	26 mOhm @ 27.5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	110nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	3600pF @ 25V
Verpackung	Tube



















































FQA47P06 ist neu im Original. Suche FQA47P06 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQA47P06 Fairchild/ON Semiconductor mit Garantie und Vertrauen.
Anfrage FQA47P06: Info@Y-IC.com

Sie können auch interessiert sein:

 FQA46P06 FSC FQA46P06 FSC	 FQA55N10 Fairchild/ON Semiconductor MOSFET N-CH 100V 61A TO-3P	 FQA46P15 Fairchild/ON Semiconductor FQA46P15 FAIRCHILD	 FQA46N15_F109 AMI Semiconductor / ON Semiconductor MOSFET N-CH 150V 50A TO-3P
 FQA46N15_F109 Fairchild/ON Semiconductor MOSFET N-CH 150V 50A TO-3P	 FQA55N10 AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 61A TO-3P	 FQA50N06 FAIRCHI FAIRCHI TO-220	 FQA48N20 Fairchild/ON Semiconductor MOSFET N-CH 200V 48A TO-3P

heiße Teile

Mehr

 FQA34N25	 FQA35N40	 FQA35N40	 FQA36P15	 FQA36P15
 FQA36P15_F109	 FQA36P15_F109	 FQA38N30	 FQA38N30	 FQA40N25
 FQA40N25	 FQA40N30	 FQA40N50	 FQA40N50L	 FQA44N10
 FQA44N10	 FQA44N30	 FQA44N30	 FQA46N15	 FQA46N15
 FQA46N15_F109	 FQA46N15_F109	 FQA46P06	 FQA46P15	 FQA47P06
 FQA48N20	 FQA48N20	 FQA55N10	 FQA55N10	 FQA55N25
 FQA55N25	 FQA62N25C	 FQA62N25C	 FQA65N06	 FQA65N06
 FQA65N20	 FQA65N20	 FQA6N90C	 FQA70N10	 FQA70N10
 FQA70N15	 FQA70N15	 FQA7N80C	 FQA7N80C	 FQA8N100C
 FQA8N100C	 FQA8N80C	 FQA8N80C	 FQA90N08	 FQA90N08

Contact us: Info@Y-IC.com

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